

Search Notes

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1161	(438/585).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/21 19:35
L2	774	(438/595).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/21 19:37
L3	214	(438/735).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/21 19:38
L4	157	(438/737).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/21 19:37
L5	530	(438/738).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/21 20:17
L6	32	"5661054"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 19:43
L7	44	"5631179"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 20:11
L9	1	"6114194".PN.	USPAT; USOCR	OR	ON	2005/02/21 20:23
L10	359	438/739	USPAT; USOCR	OR	ON	2005/02/21 20:23
S1	3022	word adj line and bit adj line and silicon adj nitride and spacer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 19:32
S2	840	word adj line and bit adj line and silicon adj nitride and spacer with silicon adj oxide	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 16:57

S3	832	word adj line and bit adj line and silicon adj nitride and spacer with silicon adj oxide and etch\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 16:59
S4	126	S3 and hot adj electrons	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 16:59
S5	76	S4 and channel adj region	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 17:00
S6	22	S5 and bpsg	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 17:02
S7	2180	(438/586).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/21 12:52
S11	2	S4 and S7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 19:33
S12	0	haufe-jurge.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 19:34
S13	2	haufe-juerg.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 19:35
S14	158	willer-josef.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 19:57
S15	0	((("6,344,692B1") or ("6,218,275B1"))).PN. or ((2002/0001936) or (2002/0117698) or (2002/0024093)).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/08 19:58

S16	1669596	"6,344,692" B1 "6,218,275" B1 2002/0001936 2002/011 "7698" 2002/0024093	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 19:58
S17	14	"6,344,692" "6,218,275" 2002/0001936 2002/0117698 2002/0024093	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 12:52
S18	720	word adj line same silicon adj oxide and bit adj line and silicon adj nitride and spacer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 06:44
S19	90	word adj line same silicon adj oxide and bit adj line and silicon adj nitride and spacer and selective adj etch\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 06:45
S20	25	word adj line same silicon adj oxide with spacer and bit adj line and silicon adj nitride and selective adj etch\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 06:45
S21	11	word adj line same silicon adj oxide with spacer and bit adj line and silicon adj nitride same selective adj etch\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 12:51
S22	11	word adj line same silicon adj oxide with spacer and bit adj line and silicon adj nitride same selective adj etch\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 12:51
S23	15	"6,344,692" "6,218,275" 2002/0001936 2002/0117698 2002/0024093	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 12:52
S24	2189	(438/586).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/21 12:53
S25	2	("5631179").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/21 12:54

S26	2	("5661054").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/21 12:55
S27	2	("5270240").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/21 12:55